**Vishay Semiconductors** 

### High Speed Infrared Emitting Diodes, 940 nm, Surface Emitter Technology



www.vishay.com

### DESCRIPTION

As part of the SurfLight<sup>TM</sup> portfolio, the VSMY2943 series are infrared, 940 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

### **APPLICATIONS**

- Miniature light barrier
- Photointerrupters
- · Optical switch
- Emitter source for proximity sensors
- IR illumination

### **FEATURES**

- Package type: surface mount
- · Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.55
- Peak wavelength: λ<sub>p</sub> = 940 nm
- · High reliability
- · High radiant power
- · Very high radiant intensity
- Angle of half intensity:  $\varphi = \pm 28^{\circ}$
- · Suitable for high pulse current operation
- · Terminal configurations: gullwing or reverse gullwing
- Package matches with detector VEMD2503X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

PRODUCT SUMMARY					
COMPONENT	l <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)	
VSMY2943RG	35	± 28	940	10	
VSMY2943G	35	± 28	940	10	

#### Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY2943RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMY2943G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

Note

· MOQ: minimum order quantity





HALOGEN FREE <u>GREEN</u> (5-2008)



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ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А	
Power dissipation		Pv	200	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	Acc. figure 7, J-STD-020	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R <sub>thJA</sub>	250	K/W	

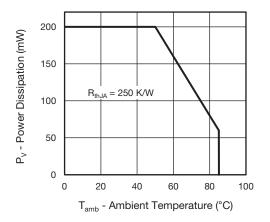


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

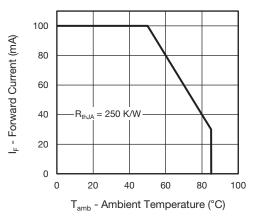


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	-	1.55	2.0	V
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>	-	2.65	-	V
Temperature coefficient of $V_F$	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>	-	-2.1	-	mV/K
Reverse current		I <sub>R</sub>	not designed for reverse operation		μA	
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0 mW/cm^{2}$	CJ	-	125	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	20	35	65	mW/sr
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>	-	300	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе	-	55	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 100 mA	ΤΚφ <sub>e</sub>	-	-0.2	-	%/K
Angle of half intensity		φ	-	± 28	-	deg
Peak wavelength	I <sub>F</sub> = 100 mA	λ <sub>p</sub>	920	940	960	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ	-	40	-	nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	ΤΚλ <sub>p</sub>	-	0.25	-	nm/K
Rise time	$I_F = 100 \text{ mA}, 20 \% \text{ to } 80 \%$	t <sub>r</sub>	-	10	-	ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>	-	10	-	ns

Document Number: 84252



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### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

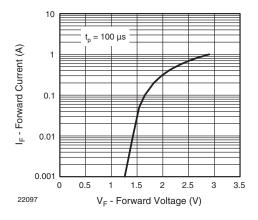


Fig. 3 - Forward Current vs. Forward Voltage

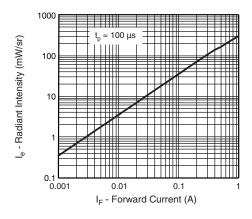


Fig. 4 - Radiant Intensity vs. Forward Current

#### SOLDER PROFILE

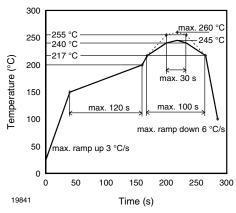


Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

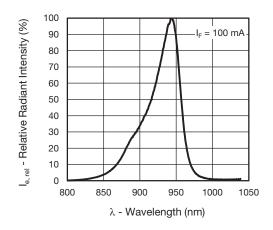


Fig. 5 - Relative Radiant Power vs. Wavelength

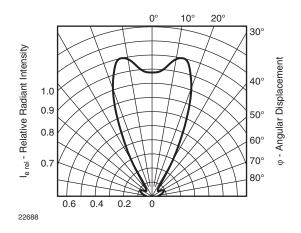


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

Moisture sensitivity level 2a, acc. to J-STD-020.

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

**3** For technical questions, contact: <u>emittertechsupport@vishay.com</u>

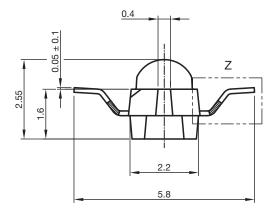


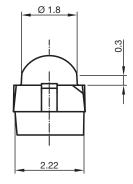


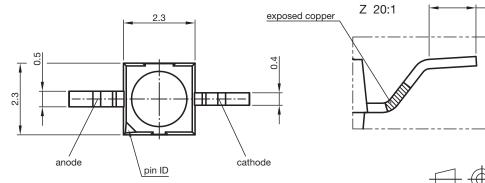
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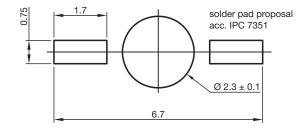
0.8

### PACKAGE DIMENSIONS in millimeters: VSMY2943RG



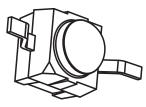






technical drawings according to DIN specifications

Not indicated tolerances ± 0.2

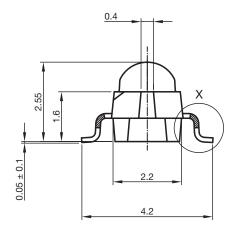


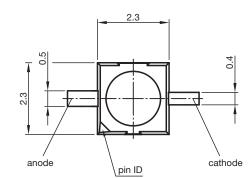
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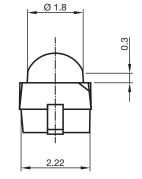


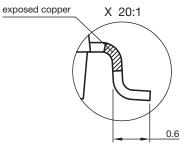
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### PACKAGE DIMENSIONS in millimeters: VSMY2943G



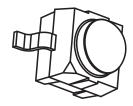


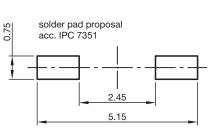






Not indicated tolerances ± 0.2



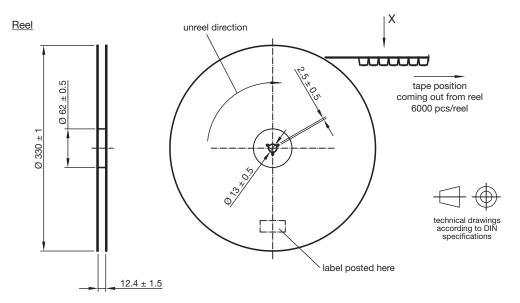


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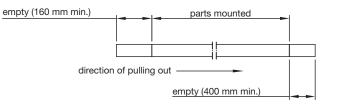


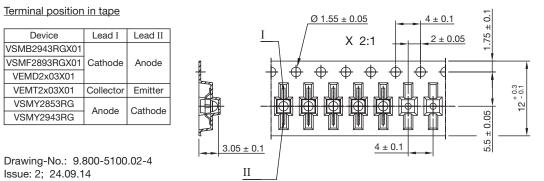
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### TAPING AND REEL DIMENSIONS in millimeters: VSMY2943RG



Leader and trailer tape

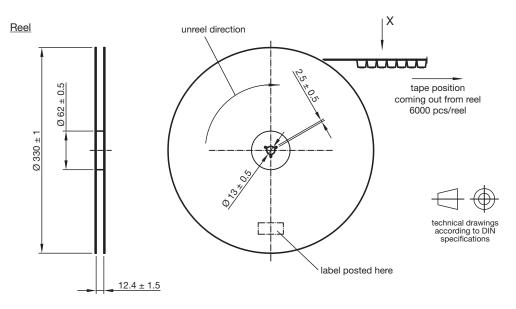




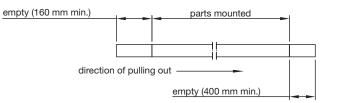


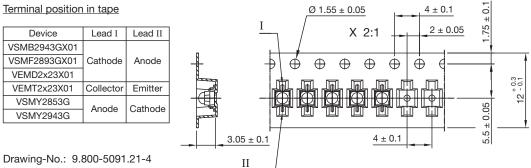
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### TAPING AND REEL DIMENSIONS in millimeters: VSMY2943G



Leader and trailer tape





Issue: 2; 24.09.14



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